


[Home](#) > [2N3622 \(#23116\)](#)

## 2N3622 (#23116)

### Products

- ▶ [Product Directory](#)
- ▶ [Applications Directory](#)
- ▶ [Parametric Search](#)

#### Overview

#### Diagrams

Electrical Rating	Symbol	Min	Typ	Max	Unit
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$			0.75	V
DC Current Gain	HFE	40.00			

Maximum Electrical Rating	Symbol	Min	Typ	Max	Unit
Breakdown Voltage, Collector-Base (Emitter Open)	$V_{BR(CBO)}$			75.00	V
Collector Current (dc)	$I_C$			5.00	A
Collector-Emitter Voltage (Base Open)	$V_{CEO}$			40.00	V
Emitter-Base Voltage (Collector Open)	$V_{EBO}$			4.00	V
Power Dissipation, Total	$P_T$			30.00	W

This part can be found in the following product categories:

- ▶ [Discretes](#) ▶ [Transistors](#) ▶ [BJT \(BiPolar Junction Transistor\)](#) ▶ [PNP Transistor](#)
- ▶ [Non-Radiation Hardened Devices](#) ▶ [Transistors](#) ▶ [BJT \(BiPolar Junction Transistor\)](#) ▶ [NPN Transistor](#)

### Related Links

- [Technical support](#)
- [Sales Contacts](#)
- [Available Stock](#)
- [Sales Contacts](#)
- [RFQ/Samples](#)